International Rectifier

March, 24th 2011

Automotive grade

AUIPS7142G

DUAL CHANNELS CURRENT SENSE HIGH SIDE SWITCH

Features

- 24V battery system
- Over current shutdown
- Over temperature shutdown
- Current sensing
- Active clamp
- Low quiescent current
- ESD protection
- Optimized Turn On/Off for EMI
- Lead free and RoHS compliant

Applications

- 21W Filament lamp
- Solenoid
- 24V truck loads

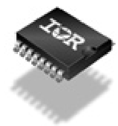
Description

The AUIPS7142G is a fully protected dual high side switch specifically designed for driving lamp. It features current sensing, over-current, over-temperature, ESD protection and drain to source active clamp. The Ifb pin is used for current sensing. The over-current shutdown is higher than inrush current of the lamp.

Product Summary

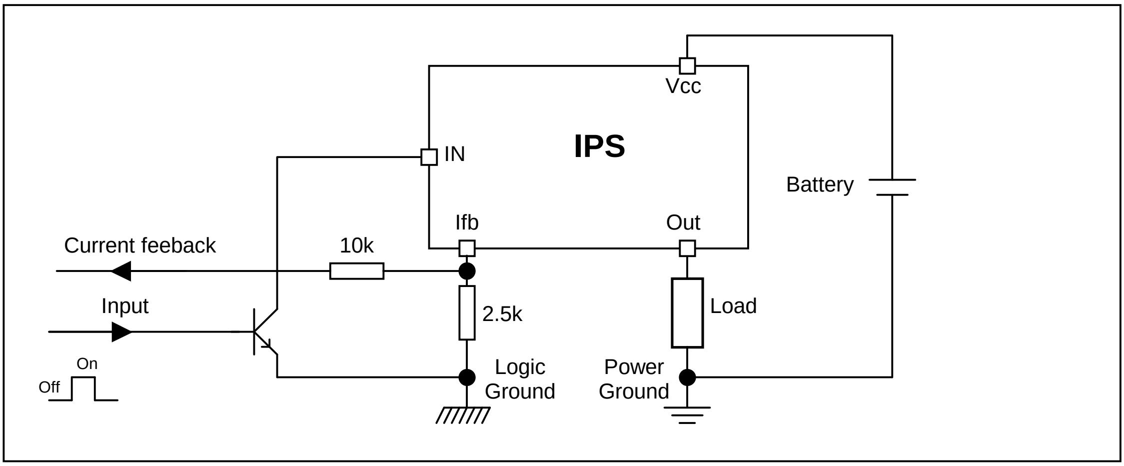
Rds(on)	100mΩ max.
Vclamp	65V
Current shutdown	20A min.

Package



SOIC16L-Wide Body

Typical Connection



Qualification Information†

Qualification Level		Automotive (per AEC-Q100††)	
		Comments: This family of ICs has passed an Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.	
Moisture Sensitivity Level		SOIC-16L WB	MSL2, 260°C (per IPC/JEDEC J-STD-020)
ESD	Machine Model	Class M4 (+/-450V) (per AEC-Q100-003)	
	Human Body Model	Class H2 (+/-4000V) (per AEC-Q100-002)	
	Charged Device Model	Class C4 (+/-1000V) (per AEC-Q100-011)	
IC Latch-Up Test		ClassII, Level A (per AEC-Q100-004)	
RoHS Compliant		Yes	

† Qualification standards can be found at International Rectifier's web site http://www.irf.com/
†† Exceptions to AEC-Q100 requirements are noted in the qualification report.

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. (Tj= -40°C..150°C, Vcc=6..50V unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
Vout	Maximum output voltage	Vcc-60	Vcc+0.3	V
I rev	Maximum reverse pulsed current (t=100µs) see page 8	—	30	A
Isd cont.	Maximum diode continuous current Tambient=25°C, Rth=40°C/W / per channel	—	1.7	A
Vcc-Vin max.	Maximum Vcc voltage	-16	60	V
Iifb, max.	Maximum feedback current	-50	10	mA
Vcc sc.	Maximum Vcc voltage with short circuit protection see page 8	—	50	V
Pd	Maximum power dissipation (internally limited by thermal protection)			W
	Rth=40°C/W	—	3	
Tj max.	Max. storage & operating junction temperature	-40	150	°C

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
Rth1	Thermal resistance junction to ambient 6cm² footprint one Mosfet on	45	—	°C/W
Rth2	Thermal resistance junction to ambient 6cm² footprint two Mosfet on	40	—	°C/W

note : Tj-Tambient=Power dissipated in the 2 channel x Rth

Recommended Operating Conditions

These values are given for a quick design.

Symbol	Parameter	Min.	Max.	Units
Iout	Continuous output current, Tambient=85°C, Tj=125°C Rth=40°C/W, 6cm² footprint	—	1.5	A
RIfb	Ifb resistor	1.5	—	kΩ

Static Electrical Characteristics

Tj=-40°C..150°C, Vcc=6-50V (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Vcc op.	Operating voltage	6	—	60	V	
Rds(on)	ON state resistance Tj=25°C	—	75	100	mΩ	Ids=2A
	ON state resistance Tj=150°C(2)	—	135	180		
Icc off	Supply leakage current	—	1	3	µA	Vin=Vcc / Vifb=Vgnd Vout=Vgnd, Tj=25°C
Iout off	Output leakage current	—	1	3		
I in on	Input current while on	0.6	2	4	mA	Vcc-Vin=28V, Tj=25°C
V clamp1	Vcc to Vout clamp voltage 1	60	64	—	V	Id=10mA
V clamp2	Vcc to Vout clamp voltage 2	60	65	72		Id=6A see fig. 2
Vih(1)	High level Input threshold voltage	—	3	5		Id=10mA
Vil(1)	Low level Input threshold voltage	1.5	2.3	—		
Vf	Forward body diode voltage Tj=25°C	—	0.8	0.9		If=1A
	Forward body diode voltage Tj=125°C	—	0.65	0.75		

(1) Input thresholds are measured directly between the input pin and Vcc.

Switching Electrical Characteristics

Vcc=28V, Resistive load=27Ω, Tj=-40°C..150°C

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Tdon	Turn on delay time to 20%	4	10	20	µs	See fig. 1
Tr	Rise time from 20% to 80% of Vcc	2	5	10		
Tdoff	Turn off delay time	20	40	80	µs	
Tf	Fall time from 80% to 20% of Vcc	2.5	5	10		

Protection Characteristics

Tj=-40°C..150°C, Vcc=6-50V (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Tsd	Over temperature threshold	150(2)	165	—	°C	See fig. 3 and fig.11
Isd	Over-current shutdown	20	25	37	A	See fig. 3 and page 7
I fault	Ifb after an over-current or an over-temperature (latched)	2.2	3	5	mA	See fig. 3

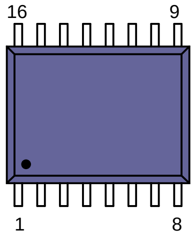
Current Sensing Characteristics

Tj=-40°C..150°C, Vcc=6-50V (unless otherwise specified). Specified 500µs after the turn on. Vcc-Vifb>4V

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Ratio	I load / Ifb current ratio	2000	2400	2800		Iload<4A
Ratio_TC	I load / Ifb variation over temperature(2)	-5%	0	+5	%	Tj=-40°C to +150°C
I offset	Load current offset	-0.02	0	0.02	A	Iout<4A
Ifb leakage	Ifb leakage current On in open load	0	1	10	µA	Iout=0A, Vcc-Vin=28V

(2) Guaranteed by design

Lead Assignments

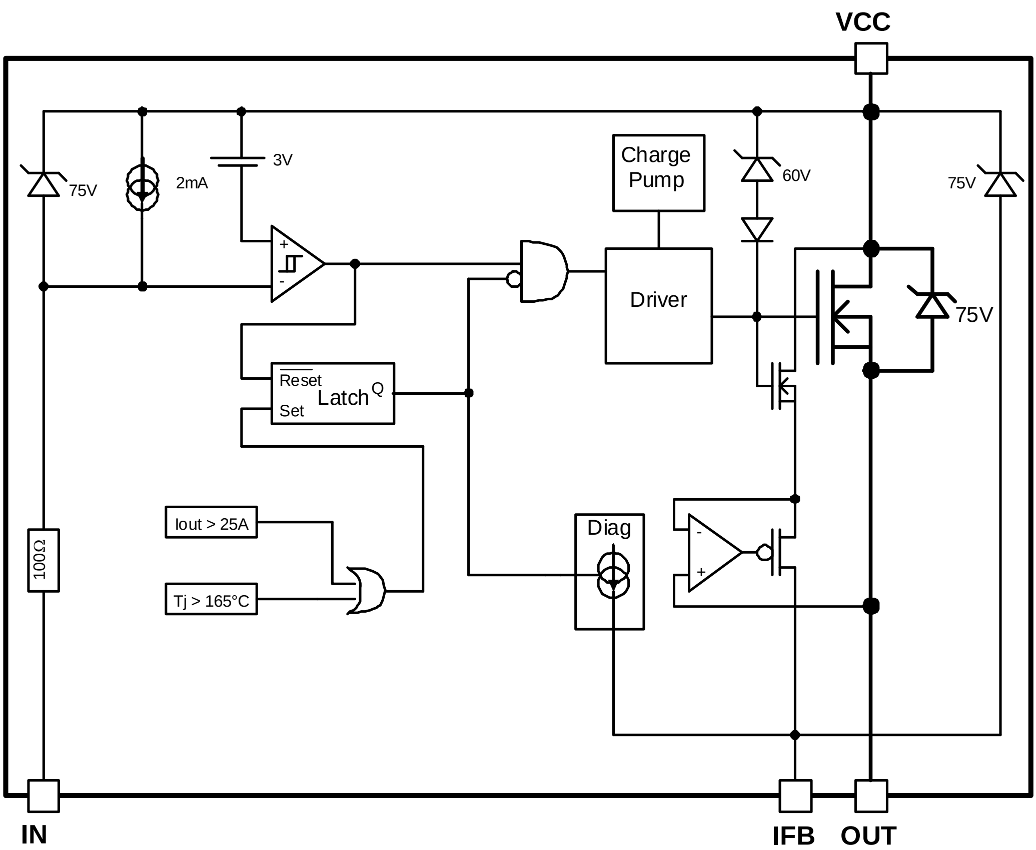


SO16W

1-2- Vcc
3- In1
4- Ifb1
5- In2
6- Ifb2
7-8-9-Vcc
10-11-12- Out2
13-14-15- Out1
16- Vcc

Functional Block Diagram

All values are typical



Truth Table

Op. Conditions	Input	Output	Ifb pin voltage
Normal mode	H	L	0V
Normal mode	L	H	I load x Rfb / Ratio
Open load	H	L	0V
Open load	L	H	0V
Short circuit to GND	H	L	0V
Short circuit to GND	L	L	V fault (latched)
Over temperature	H	L	0V
Over temperature	L	L	V fault (latched)

Operating voltage

Maximum Vcc voltage : this is the maximum voltage before the breakdown of the IC process.
Operating voltage : This is the Vcc range in which the functionality of the part is guaranteed. The AEC-Q100 qualification is run at the maximum operating voltage specified in the datasheet.

Reverse battery

During the reverse battery the Mosfet is kept off and the load current is flowing into the body diode of the power Mosfet.
Power dissipation in the IPS : P = I load * Vf
There is no protection, so Tj must be lower than 150°C in the worst case condition of current and ambient temperature.
If the power dissipation is too high in Rifb, a diode in serial can be added to block the current.
The transistor used to pull-down the input should be a bipolar in order to block the reverse current. The 100ohm input resistor can not sustain continuously 16V (see Vcc-Vin max. in the Absolute Maximum Ratings section)

Active clamp

The purpose of the active clamp is to limit the voltage across the MOSFET to a value below the body diode break down voltage to reduce the amount of stress on the device during switching.
The temperature increase during active clamp can be estimated as follows:

$$\Delta_{Tj} = P_{CL} \cdot Z_{TH}(t_{CLAMP})$$

Where: $Z_{TH}(t_{CLAMP})$ is the thermal impedance at t_{CLAMP} and can be read from the thermal impedance curves given in the data sheets.

$P_{CL} = V_{CL} \cdot I_{CLavg}$: Power dissipation during active clamp

$V_{CL} = 65V$: Typical V_{CLAMP} value.

$I_{CLavg} = \frac{I_{CL}}{2}$: Average current during active clamp

$t_{CL} = \frac{I_{CL}}{\left|\frac{di}{dt}\right|}$: Active clamp duration

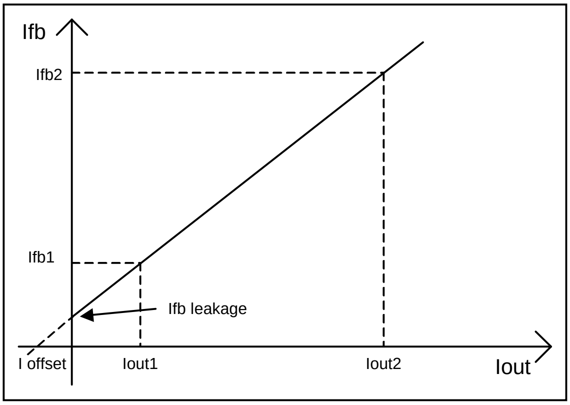
$\frac{di}{dt} = \frac{V_{Battery} - V_{CL}}{L}$: Demagnetization current

Figure 9 gives the maximum inductance versus the load current in the worst case : the part switch off after an over temperature detection. If the load inductance exceed the curve, a free wheeling diode is required.

Over-current protection

The threshold of the over-current protection is set in order to guaranteed that the device is able to turn on a load with an inrush current lower than the minimum of Isd. Nevertheless for high current and high temperature the device may switch off for a lower current due to the over-temperature protection. This behavior is shown in Figure 11.

Current sensing accuracy

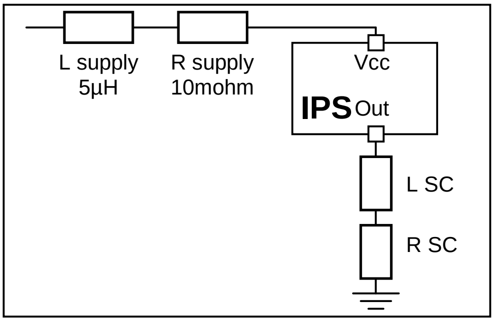


The current sensing is specified by measuring 3 points :
- Ifb1 for Iout1
- Ifb2 for Iout2
- Ifb leakage for Iout=0

The parameters in the datasheet are computed with the following formula :
Ratio = (Iout2 – Iout1)/(Ifb2 – Ifb1)
I offset = Ifb1 x Ratio – Iout1
This allows the designer to evaluate the Ifb for any Iout value using :
Ifb = (Iout + I offset) / Ratio if Ifb > Ifb leakage
For some applications, a calibration is required. In that case, the accuracy of the system will depends on the variation of the I offset and the ratio over the temperature range. The ratio variation is given by Ratio_TC specified in page 4.
The Ioffset variation depends directly on the Rdson :
I offset@-40°C= I offset@25°C / 0.8
I offset@150°C= I offset@25°C / 1.9

Maximum Vcc voltage with short circuit protection

The maximum Vcc voltage with short circuit is the maximum voltage for which the part is able to protect itself under test conditions representative of the application. 2 kind of short circuits are considered : terminal and load short circuit.



	L SC	R SC
Terminal SC	0.1 µH	10 mohm
Load SC	10 µH	100 mohm

Maximum current during reverse circulation

In case of short circuit to battery, a voltage drop of the Vcc may create a current which circulate in reverse mode. When the device is on, this reverse circulation current will not trigger the internal fault latch. This immunization is also true when the part turns on while a reverse current flows into the device. The maximum current (I rev) is specified in the maximum rating section.

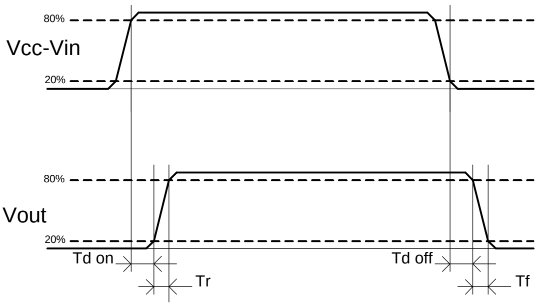


Figure 1 – IN rise time & switching definitions

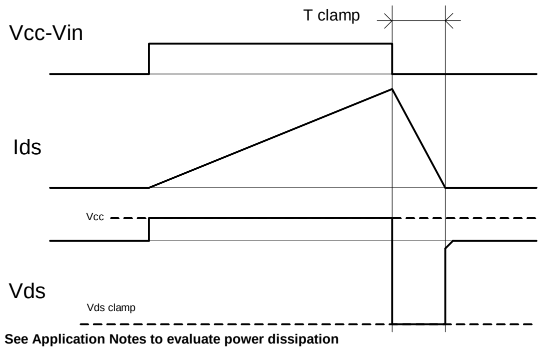


Figure 2 – Active clamp waveforms

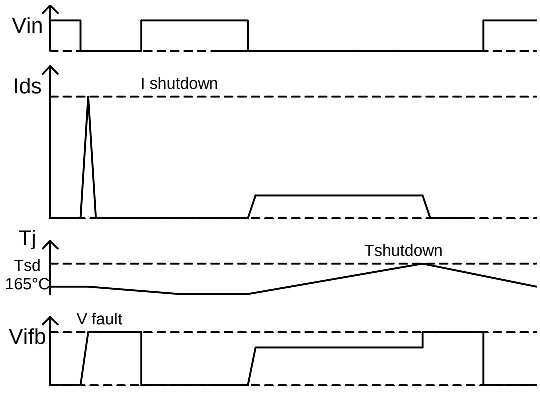


Figure 3 – Protection timing diagram

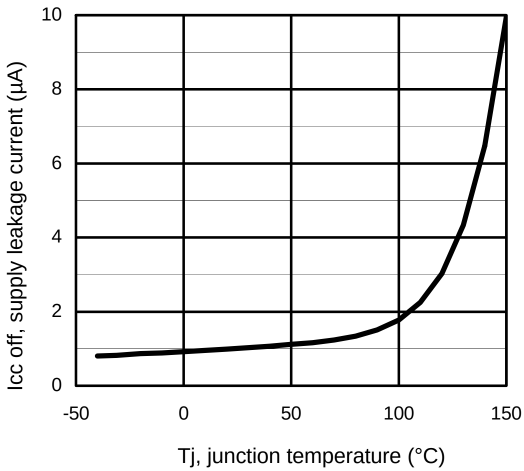


Figure 4 – Icc off (µA) Vs Tj (°C)

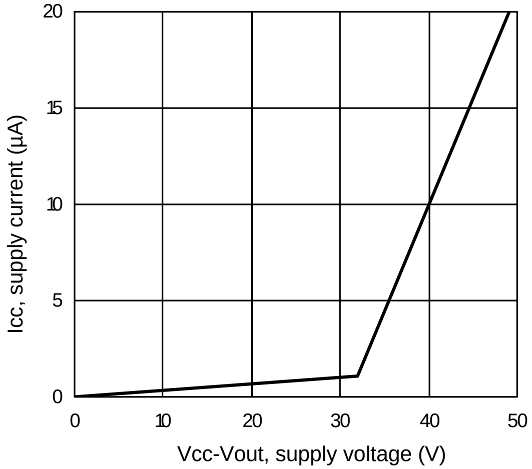


Figure 5 – Icc off (µA) Vs Vcc-Vout (V)

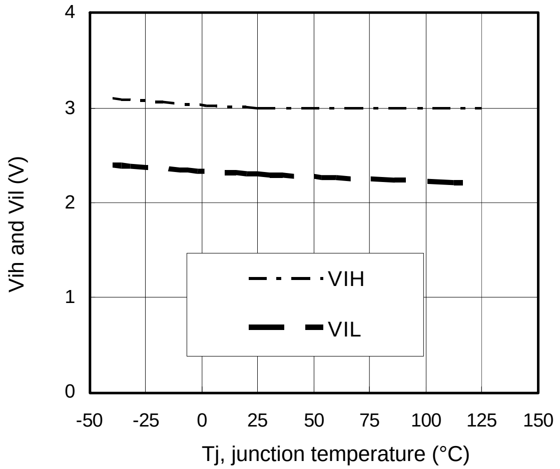


Figure 6 – Vih and Vil (V) Vs Tj (°C)

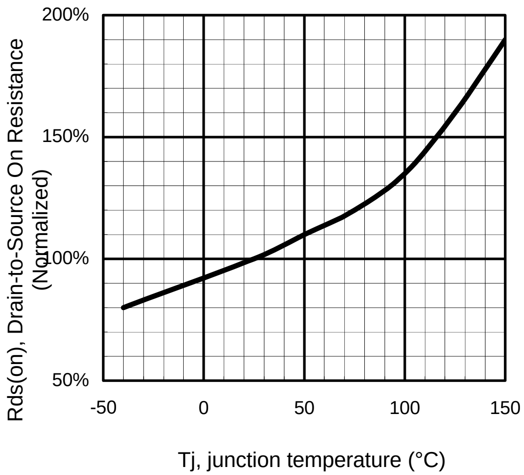


Figure 7 - Normalized Rds(on) (%) Vs Tj (°C)

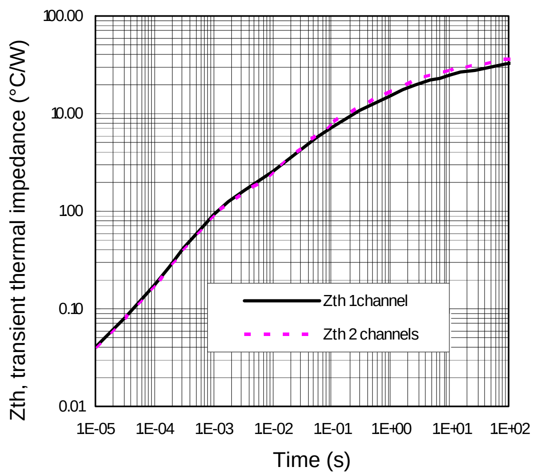


Figure 8 – Transient thermal impedance (°C/W) Vs time (s)

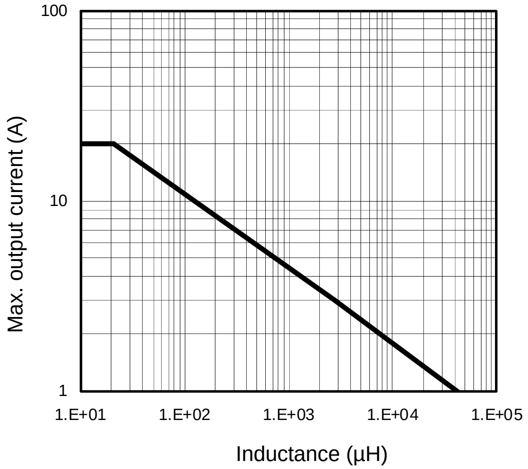


Figure 9 – Max. Iout (A) Vs inductance (µH)

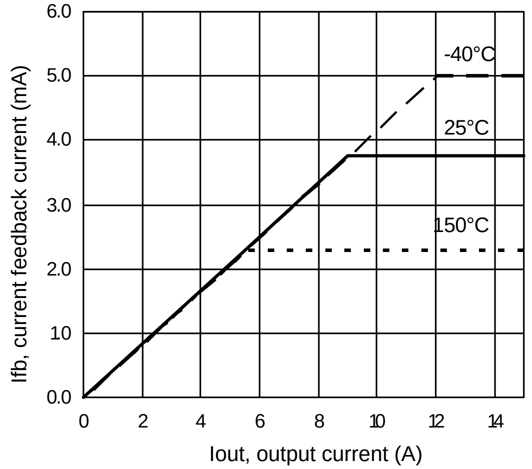


Figure 10 – Ifb (mA) Vs Iout (A)

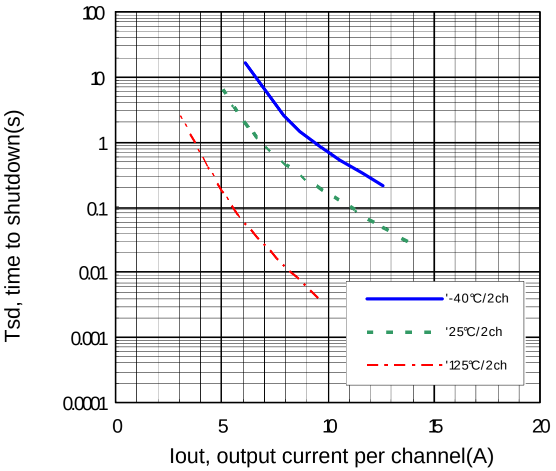
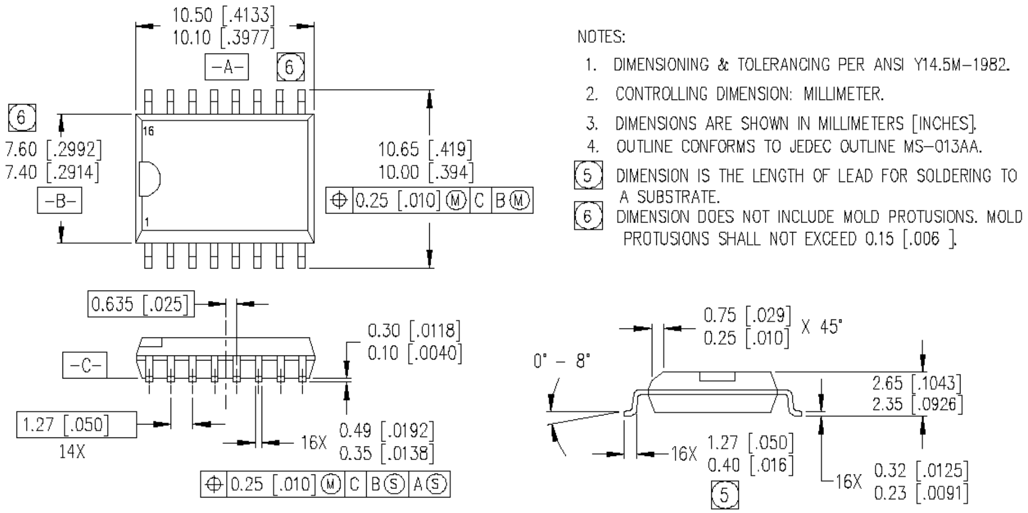


Figure 11 – Tsd (s) Vs I out (A)
2 channels on

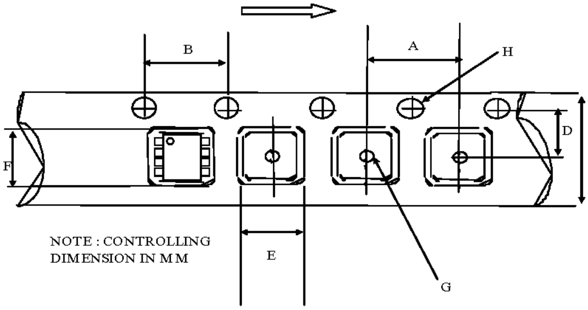
Case Outline SOIC16W



NOTES:
1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-013AA.
5. DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.
6. DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.15 [.006].

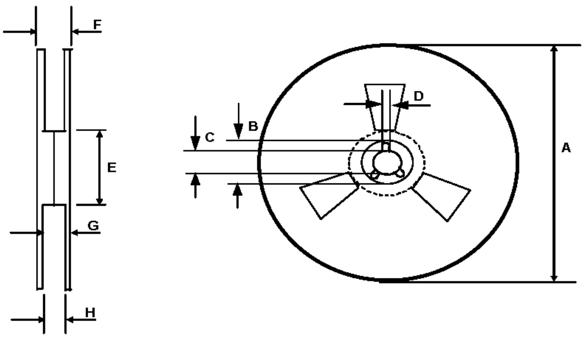
16 Lead SOIC (wide body)

Tape and Reel – SOIC16W



CARRIER TAPE DIMENSION FOR 16SOICW

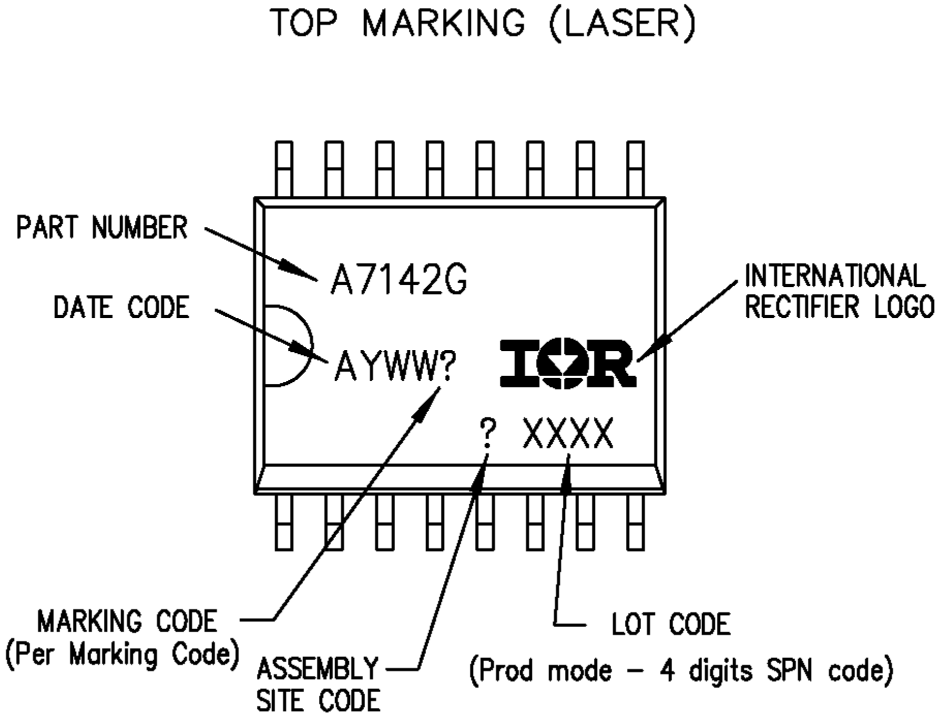
Code	Metric		Imperial	
	Min	Max	Min	Max
A	11.90	12.10	0.468	0.476
B	3.90	4.10	0.153	0.161
C	15.70	16.30	0.618	0.641
D	7.40	7.60	0.291	0.299
E	10.80	11.00	0.425	0.433
F	10.60	10.80	0.417	0.425
G	1.50	n/a	0.059	n/a
H	1.50	1.60	0.059	0.062



REEL DIMENSIONS FOR 16SOICW

Code	Metric		Imperial	
	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
B	20.95	21.45	0.824	0.844
C	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	22.40	n/a	0.881
G	18.50	21.10	0.728	0.830
H	16.40	18.40	0.645	0.724

Part Marking Information



Ordering Information

Base Part Number	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIPS7142G	SO28W	Tube	45	AUIPS7142G
		Tape and reel	1500	AUIPS7142GTR

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Revision History

Revision	Date	Notes/Changes
A3	April, 29th 2010	Add tri-temp limits
A4	March, 17th 2011	Au release
A5	March,18th 2011	Update lead free and RoHS 1st page
A6	March, 24th 2011	Add Tape and reel information

单击下面可查看定价，库存，交付和生命周期等信息

>>Infineon Technologies(英飞凌)